



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Kusumoto et al. Art Unit : 2814
Serial No.: 09/903,339 Examiner : Unknown
Filed : July 10, 2001
Title : METHOD FOR PRODUCING INSULATED GATE THIN FILM
SEMICONDUCTOR DEVICE

#3
Pre Amt. B
2-14-02
Retained

Commissioner for Patents
Washington, D.C. 20231

PRELIMINARY AMENDMENT

Prior to examination, please amend the application as follows:

In the claims:

Add claims 21-30 as follows:

B' - 21. (New) A method of manufacturing a semiconductor device comprising the steps of:

forming an amorphous semiconductor film over a substrate;

01/28/2002 NMOHAMM1 00000168 061050 09903339

01 FC:103 180.00 OP
02 FC:102 168.00 CH 336.00 OP

Adjustment date: 01/29/2002 NMOHAMM1
01/28/2002 NMOHAMM1 00000168 061050 09903339
02 FC:102 168.00 CH 336.00 OP

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CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR \$1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

October 10, 2001

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